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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	180MHz
Connectivity	CSIO, EBI/EMI, I²C, LINbus, SmartCard, SPI, UART/USART, USB
Peripherals	DMA, I²S, LVD, POR, PWM, WDT
Number of I/O	121
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 24x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/s6e2g36h0agv2000a

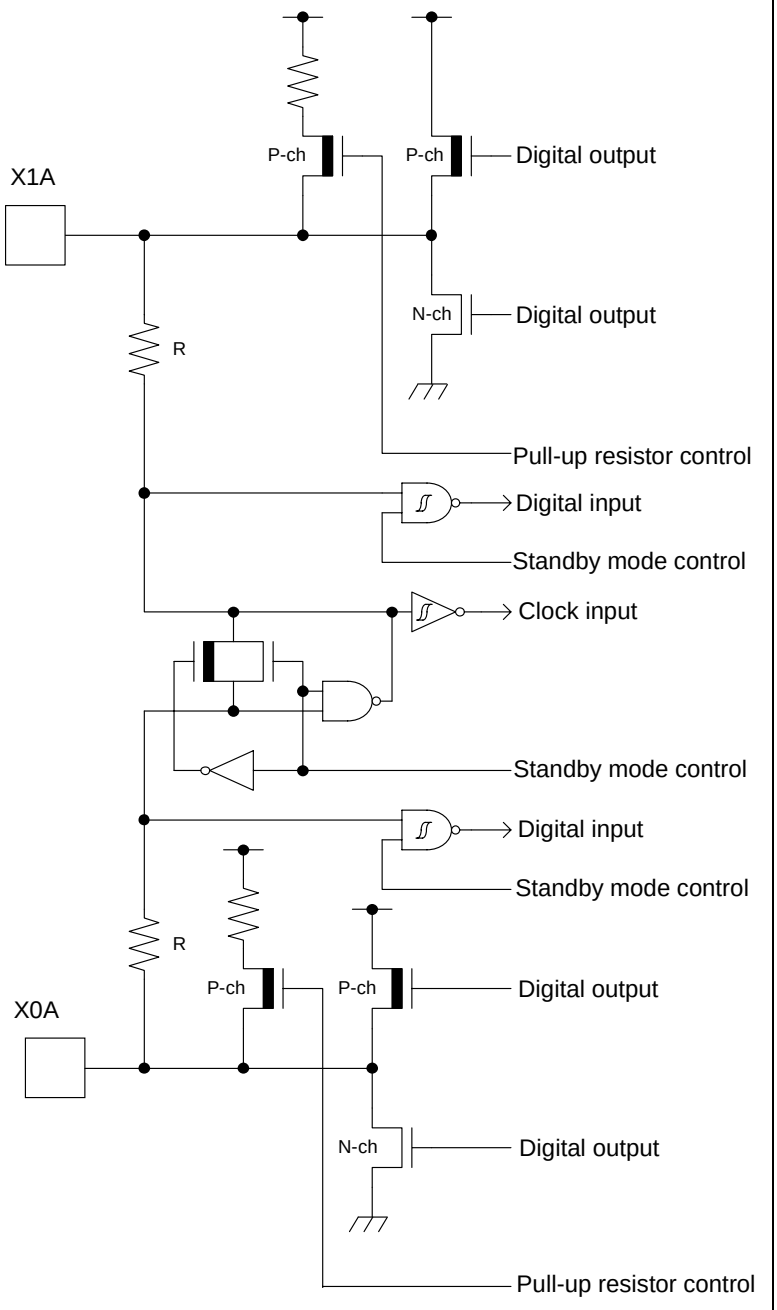
Pin Number		Pin Name	I/O Circuit Type	Pin State Type
LQFP-176	LQFP-144			
18	15	PAD	N	I
		SCK3_0 (SCL3_0)		
		TIOB9_0		
		MADATA13_0		
19	16	PAE	N	I
		ADTG_0		
		SOT3_0 (SDA3_0)		
		TIOB10_0		
		MADATA14_0		
20	17	PAF	I	K
		SIN3_0		
		TIOB11_0		
		INT16_0		
		MADATA15_0		
21	18	P08	E	K
		TIOB12_0		
		INT17_0		
		MDQM0_0		
22	19	P09	E	K
		TIOB13_0		
		INT18_0		
		MDQM1_0		
23	20	P0A	L	I
		ADTG_1		
		MCLKOUT_0		
24	-	P30	E	K
		MI2SWS1_1		
		RX0_1		
		TIOB11_2		
		INT01_2		
25	-	P31	E	I
		MI2SMCK1_1		
		TX0_1		
		TIOA12_2		
26	21	P32	L	K
		INT19_0		
		S_DATA1_0		
27	22	P33	L	I
		FRCK0_0		
		S_DATA0_0		

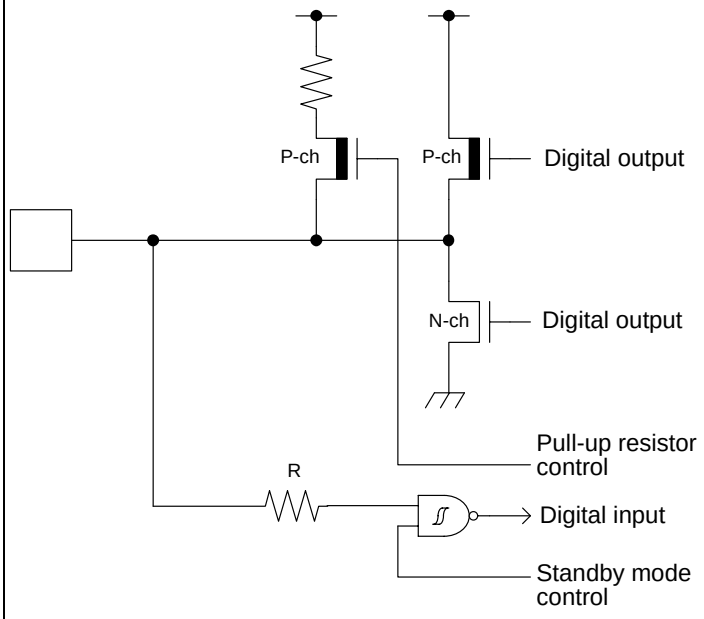
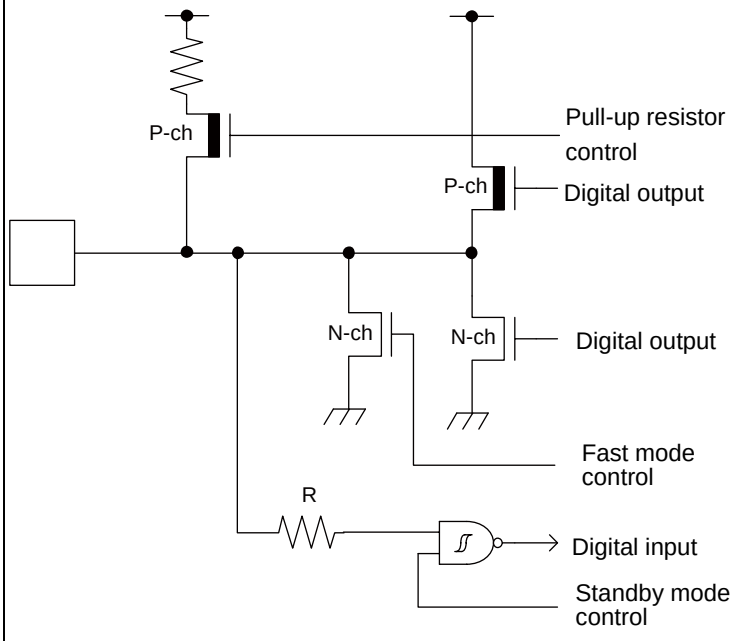
Pin Number		Pin Name	I/O Circuit Type	Pin State Type
LQFP-176	LQFP-144			
141	-	P92	E	K
		SOT5_1 (SDA5_1)		
		RTO12_1 (PPG12_1)		
		TIOB2_1		
		INT14_1		
		IC0_VPEN_1		
142	-	P93	E	K
		SCK5_1 (SCL5_1)		
		RTO13_1 (PPG13_1)		
		TIOB3_1		
		INT15_1		
		IC0_RST_1		
143	-	P94	E	I
		CTS5_1		
		RTO14_1 (PPG14_1)		
		TIOB4_1		
		IC0_DATA_1		
144	-	P95	E	I
		RTS5_1		
		RTO15_1 (PPG15_1)		
		TIOB5_1		
		IC0_CIN_1		
145	115	PC0	K	V
		E_RXER		
146	116	PC1	K	V
		TIOB6_0		
		E_RX03		
147	117	PC2	K	V
		TIOA6_0		
		E_RX02		
148	118	PC3	K	V
		TIOB7_0		
		E_RX01		
149	119	PC4	K	V
		TIOA7_0		
		E_RX00		
150	120	PC5	K	V
		TIOB14_0		
		E_RXDV		

Module	Pin Name	Function	Pin Number	
			LQFP 176	LQFP 144
Base Timer 0	TIOA0_0	Base Timer ch 0 TIOA pin	46	38
	TIOA0_1		35	30
	TIOA0_2		94	78
	TIOB0_0	Base Timer ch 0 TIOB pin	69	59
	TIOB0_1		139	-
	TIOB0_2		95	79
Base Timer 1	TIOA1_0	Base Timer ch 1 TIOA pin	47	39
	TIOA1_1		36	31
	TIOA1_2		96	80
	TIOB1_0	Base Timer ch 1 TIOB pin	70	60
	TIOB1_1		140	-
	TIOB1_2		97	81
Base Timer 2	TIOA2_0	Base Timer ch 2 TIOA pin	48	40
	TIOA2_1		37	32
	TIOA2_2		98	82
	TIOB2_0	Base Timer ch 2 TIOB pin	71	61
	TIOB2_1		141	-
	TIOB2_2		99	83
Base Timer 3	TIOA3_0	Base Timer ch 3 TIOA pin	49	41
	TIOA3_1		38	33
	TIOA3_2		106	86
	TIOB3_0	Base Timer ch 3 TIOB pin	72	62
	TIOB3_1		142	-
	TIOB3_2		107	87
Base Timer 4	TIOA4_0	Base Timer ch 4 TIOA pin	50	42
	TIOA4_1		39	34
	TIOA4_2		108	88
	TIOB4_0	Base Timer ch 4 TIOB pin	73	63
	TIOB4_1		143	-
	TIOB4_2		109	89
Base Timer 5	TIOA5_0	Base Timer ch 5 TIOA pin	51	43
	TIOA5_1		40	35
	TIOA5_2		114	90
	TIOB5_0	Base Timer ch 5 TIOB pin	74	64
	TIOB5_1		144	-
	TIOB5_2		115	91
Base Timer 6	TIOA6_0	Base Timer ch 6 TIOA pin	147	117
	TIOA6_1		78	-
	TIOA6_2		122	98
	TIOB6_0	Base Timer ch 6 TIOB pin	146	116
	TIOB6_1		79	-
	TIOB6_2		123	99

Module	Pin Name	Function	Pin Number	
			LQFP 176	LQFP 144
External bus	MADATA00_0	External bus interface data bus (address/data multiplex bus)	2	2
	MADATA01_0		3	3
	MADATA02_0		4	4
	MADATA03_0		5	5
	MADATA04_0		6	6
	MADATA05_0		7	7
	MADATA06_0		8	8
	MADATA07_0		9	9
	MADATA08_0		13	10
	MADATA09_0		14	11
	MADATA10_0		15	12
	MADATA11_0		16	13
	MADATA12_0		17	14
	MADATA13_0		18	15
	MADATA14_0		19	16
	MADATA15_0		20	17
	MDQM0_0	External bus interface byte mask signal output pin	21	18
	MDQM1_0		22	19
	MALE_0	External bus interface address latch enable output signal for multiplex	171	139
	MRDY_0	External bus interface external RDY input signal	68	58
	MCLKOUT_0	External bus interface external clock output pin	23	20
	MNALE_0	External bus interface ALE signal to control NAND flash output pin	97	81
	MNCLE_0	External bus interface CLE signal to control NAND flash output pin	96	80
	MNREX_0	External bus interface read enable signal to control NAND flash	94	78
	MNWEX_0	External bus interface write enable signal to control NAND flash	95	79
	MOEX_0	External bus interface read enable signal for SRAM	169	137
	MWEX_0	External bus interface write enable signal for SRAM	170	138
	MSDCLK_0	SDRAM interface SDRAM clock output pin	65	55
	MSDCKE_0	SDRAM interface SDRAM clock enable pin	64	54
	MRASX_0	SDRAM interface SDRAM row active strobe pin	60	50
	MCASX_0	SDRAM interface SDRAM column active strobe pin	61	51
	MSDWEX_0	SDRAM interface SDRAM write enable pin	62	52

Module	Pin Name	Function	Pin Number	
			LQFP 176	LQFP 144
Multi-Function Serial 5	SIN5_0	Multi-function serial interface ch 5 input pin	121	97
	SIN5_1		140	-
	SOT5_0 (SDA5_0)	Multi-function serial interface ch 5 output pin This pin operates as SOT5 when it is used in a UART/CSIO/LIN (operation modes 0 to 3) and as SDA5 when it is used in an I²C (operation mode 4).	120	96
	SOT5_1 (SDA5_1)		141	-
	SCK5_0 (SCL5_0)	Multi-function serial interface ch 5 clock I/O pin This pin operates as SCK5 when it is used in a CSIO (operation mode 2) and as SCL5 when it is used in an I²C (operation mode 4).	119	95
	SCK5_1 (SCL5_1)		142	-
	CTS5_0	Multi-function serial interface ch 5 CTS input pin	118	94
	CTS5_1		143	-
	RTS5_0	Multi-function serial interface ch 5 RTS output pin	117	93
	RTS5_1		144	-
Multi-Function Serial 6	SIN6_0	Multi-function serial interface ch 6 input pin	73	63
	SIN6_1		100	84
	SOT6_0 (SDA6_0)	Multi-function serial interface ch 6 output pin This pin operates as SOT6 when it is used in a UART/CSIO/LIN (operation modes 0 to 3) and as SDA6 when it is used in an I²C (operation mode 4).	74	64
	SOT6_1 (SDA6_1)		101	85
	SCK6_0 (SCL6_0)	Multi-function serial interface ch 6 clock I/O pin This pin operates as SCK6 when it is used in a CSIO (operation mode 2) and as SCL6 when it is used in an I²C (operation mode 4).	75	65
	SCK6_1 (SCL6_1)		102	-
	SCS60_0	Multi-function serial interface ch 6 chip select 0 input/output pin	76	66
	SCS60_1		103	-
	SCS61_0	Multi-function serial interface ch 6 chip select1 input/output pin	77	67
	SCS61_1		104	-
	SCS62_0	Multi-function serial interface ch 6 chip select2 input/output pin	78	-
	SCS62_1		105	-
	SCS63_0	Multi-function serial interface ch 6 chip select3 input/output pin	79	-
	SCS63_1		110	-

Type	Circuit	Remarks
D		It is possible to select the sub oscillation/GPIO function. When the main oscillation is selected: ・ Oscillation feedback resistor: approximately 5 MΩ ・ Standby mode control When the GPIO is selected: ・ CMOS level output. ・ CMOS level hysteresis input ・ Pull-up resistor control ・ Standby mode control ・ Pull-up resistor: approximately 50 kΩ ・ I_{OH} = -4 mA, I_{OL} = 4 mA

Type	Circuit	Remarks
L		・ CMOS level output ・ CMOS level hysteresis input ・ Pull-up resistor control ・ Standby mode control ・ Pull-up resistor: approximately 50 kΩ ・ I_{OH} = -8 mA, I_{OL} = 8 mA ・ When this pin is used as an I^2C pin, the digital output P-ch transistor is always off.
N		・ CMOS level output ・ CMOS level hysteresis input ・ 5V tolerant ・ Pull-up resistor control ・ Standby mode control ・ Pull-up resistor: approximately 50 kΩ ・ I_{OH} = -4 mA, I_{OL} = 4 mA (GPIO) ・ I_{OL} = 20mA (Fast mode Plus) ・ Available to control of PZR register (pseudo-open drain control) ・ For PZR registers, refer to GPIO in the FM4 Family Peripheral Manual Main Part (002-04856). ・ When this pin is used as an I^2C pin, the digital output P-ch transistor is always off.

Surface Mount Type

Surface mount packaging has longer and thinner leads than lead-insertion packaging, and therefore leads are more easily deformed or bent. The use of packages with higher pin counts and narrower pin pitch results in increased susceptibility to open connections caused by deformed pins, or shorting due to solder bridges.

You must use appropriate mounting techniques. Cypress recommends the solder reflow method, and has established a ranking of mounting conditions for each product. Users are advised to mount packages in accordance with Cypress ranking of recommended conditions.

Lead-Free Packaging

CAUTION: When ball grid array (BGA) packages with Sn-Ag-Cu balls are mounted using Sn-Pb eutectic soldering, junction strength may be reduced under some conditions of use.

Storage of Semiconductor Devices

Because plastic chip packages are formed from plastic resins, exposure to natural environmental conditions will cause absorption of moisture. During mounting, the application of heat to a package that has absorbed moisture can cause surfaces to peel, reducing moisture resistance and causing packages to crack. To prevent this, do the following:

1. Avoid exposure to rapid temperature changes, which can cause moisture to condense inside the product. Store products in locations where temperature changes are slight.
2. Use dry boxes for product storage. Products should be stored below 70% relative humidity, and at temperatures between 5°C and 30°C.
3. When Dry Packages are opened, it is recommended to have humidity between 40% and 70%.
4. When necessary, Cypress packages semiconductor devices in highly moisture-resistant aluminum laminate bags, with a silica gel desiccant. Devices should be sealed in these aluminum laminate bags for storage.
5. Avoid storing packages where they are exposed to corrosive gases or high levels of dust.

Baking

Packages that have absorbed moisture may be de-moisturized by baking (heat drying). Follow the Cypress recommended conditions for baking.

Condition: 125°C/24 h

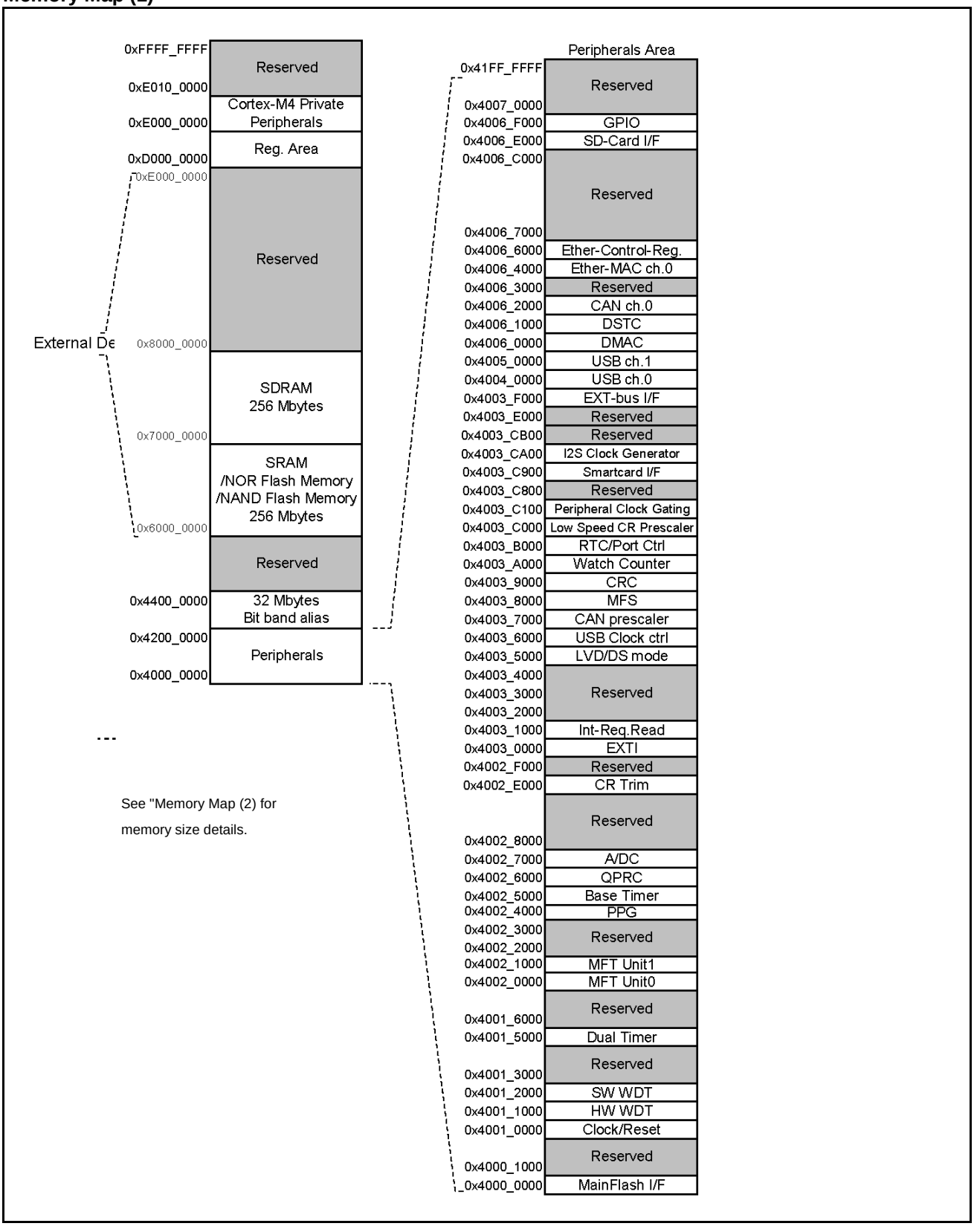
Static Electricity

Because semiconductor devices are particularly susceptible to damage by static electricity, you must take the following precautions:

1. Maintain relative humidity in the working environment between 40% and 70%. Use of an apparatus for ion generation may be needed to remove electricity.
2. Electrically ground all conveyors, solder vessels, soldering irons, and peripheral equipment.
3. Eliminate static body electricity by the use of rings or bracelets connected to ground through high resistance (on the level of 1 MΩ). Wearing of conductive clothing and shoes, and the use of conductive floor mats and other measures to minimize shock loads is recommended.
4. Ground all fixtures and instruments, or protect with anti-static measures.
5. Avoid the use of Styrofoam or other highly static-prone materials for storage of completed board assemblies.

10. Memory Map

Memory Map (1)



11. Pin Status in Each CPU State

The terms used for pin status have the following meanings:

- INITX = 0

  This is the period when the INITX pin is at the L level.

- INITX = 1

  This is the period when the INITX pin is at the H level.

- SPL = 0

  This is the status that the standby pin level setting bit (SPL) in the standby mode control register (STB_CTL) is set to 0.

- SPL = 1

  This is the status that the standby pin level setting bit (SPL) in the standby mode control register (STB_CTL) is set to 1.

- Input enabled

  Indicates that the input function can be used.

- Internal input fixed at 0

  This is the status that the input function cannot be used. Internal input is fixed at L.

- Hi-Z

  Indicates that the pin drive transistor is disabled and the pin is put in the Hi-Z state.

- Setting disabled

  Indicates that the setting is disabled.

- Maintain previous state

  Maintains the state that was immediately prior to entering the current mode.
  If a built-in peripheral function is operating, the output follows the peripheral function.
  If the pin is being used as a port, that output is maintained.

- Analog input is enabled

  Indicates that the analog input is enabled.

- Trace output

  Indicates that the trace function can be used.

- GPIO selected

  In Deep standby mode, pins switch to the general-purpose I/O port.

- Setting prohibition

  Prohibition of a setting by specification limitation

Table 12-2 Typical and Maximum Current Consumption in Normal Operation (PLL), Code with Data Accessing Running from Flash Memory (Flash Accelerator Mode and Trace Buffer Function Disabled)

Parameter	Symbol	Pin Name	Conditions		Frequency*4	Value		Unit	Remarks
						Typ*1	Max*2		
Power supply current	I_{CC}	VCC	Normal operation *7,*8 (PLL)	*5	180 MHz	82	140	mA	*3 When all peripheral clocks are on
				*6	160 MHz	74	132	mA	
					144 MHz	68	126	mA	
					120 MHz	58	116	mA	
					100 MHz	49	107	mA	
					80 MHz	40	98	mA	
					60 MHz	31	89	mA	
					40 MHz	22	80	mA	
					20 MHz	13	71	mA	
					8 MHz	7.5	65	mA	
					4 MHz	5.6	63	mA	
				*5	180 MHz	48	106	mA	*3 When all peripheral clocks are off
				*6	160 MHz	44	102	mA	
					144 MHz	41	99	mA	
					120 MHz	35	93	mA	
					100 MHz	30	88	mA	
					80 MHz	25	83	mA	
					60 MHz	20	78	mA	
					40 MHz	14	72	mA	
					20 MHz	8.7	66	mA	
					8 MHz	5.6	63	mA	
					4 MHz	4.5	62	mA	

1: T_A = +25 °C, V_{CC} = 3.3 V

2: T_J = +125 °C, V_{CC} = 5.5 V

3: When all ports are input and are fixed at 0

4: Frequency is a value of HCLK when PCLK0 = PCLK1 = PCLK2 = HCLK

5: When stopping flash accelerator mode and trace buffer function (FRWTR.RWT = 11, FBFCR.BE = 0)

6: When stopping flash accelerator mode and trace buffer function (FRWTR.RWT = 10, FBFCR.BE = 0)

7: With data access to a MainFlash memory.

8: When using the crystal oscillator of 4 MHz (including the current consumption of the oscillation circuit)

Table 12-4 Typical and Maximum Current Consumption in Normal Operation (Other than PLL), Code with Data Accessing Running from Flash Memory (Flash 0 Wait-Cycle Mode and Read Access 0 Wait)

Parameter	Symbol	Pin Name	Conditions		Frequency*4	Value		Unit	Remarks
						Typ*1	Max*2		
Power supply current	I_{CC}	VCC	Normal operation *6, *7 (main oscillation)	*5	4 MHz	4.3	62	mA	*3 When all peripheral clocks are on
						3.7	61	mA	*3 When all peripheral clocks are off
			Normal operation *6 (built-in High-speed CR)	*5	4 MHz	3.5	61	mA	*3 When all peripheral clocks are on
						2.9	60	mA	*3 When all peripheral clocks are off
			Normal operation *6, *8 (sub oscillation)	*5	32 kHz	0.47	58	mA	*3 When all peripheral clocks are on
						0.46	58	mA	*3 When all peripheral clocks are off
			Normal operation *6 (built-in low-speed CR)	*5	100 kHz	0.51	58	mA	*3 When all peripheral clocks are on
						0.50	58	mA	*3 When all peripheral clocks are off

1: T_A = +25 °C, V_{CC} = 3.3 V

2: T_J = +125 °C, V_{CC} = 5.5 V

3: When all ports are input and are fixed at 0

4: Frequency is a value of HCLK when PCLK0 = PCLK1 = PCLK2 = HCLK/2

5: When operating flash 0 wait-cycle mode and read access 0 wait (FRWTR.RWT = 00, FBFCR.SD = 000)

6: With data access to a MainFlash memory.

7: When using the crystal oscillator of 4 MHz (including the current consumption of the oscillation circuit)

8: When using the crystal oscillator of 32 kHz (including the current consumption of the oscillation circuit)

Table 12-7 Typical and Maximum Current Consumption in Sleep Operation (Other than PLL), when PCLK0 = PCLK1 = PCLK2 = HCLK/2

Parameter	Symbol	Pin Name	Conditions	Frequency*4	Value		Unit	Remarks
					Typ*1	Max*2		
Power supply current	I_{CCS}	VCC	Sleep operation*5 (main oscillation)	4 MHz	2.6	60	mA	*3 When all peripheral clocks are on
					2.0	60	mA	*3 When all peripheral clocks are off
			Sleep operation (built-in High-speed CR)	4 MHz	2.0	60	mA	*3 When all peripheral clocks are on
					1.3	59	mA	*3 When all peripheral clocks are off
			Sleep operation*6 (sub oscillation)	32 kHz	0.46	58	mA	*3 When all peripheral clocks are on
					0.45	58	mA	*3 When all peripheral clocks are off
			Sleep operation (built-in low-speed CR)	100 kHz	0.47	58	mA	*3 When all peripheral clocks are on
					0.46	58	mA	*3 When all peripheral clocks are off

1: T_A = +25 °C, V_{CC} = 3.3 V

2: T_J = +125 °C, V_{CC} = 5.5 V

3: When all ports are input and are fixed at 0.

4: Frequency is a value of HCLK when PCLK0 = PCLK1 = PCLK2 = HCLK/2

5: When using the crystal oscillator of 4 MHz (including the current consumption of the oscillation circuit)

6: When using the crystal oscillator of 32 kHz (including the current consumption of the oscillation circuit)

12.4 AC Characteristics

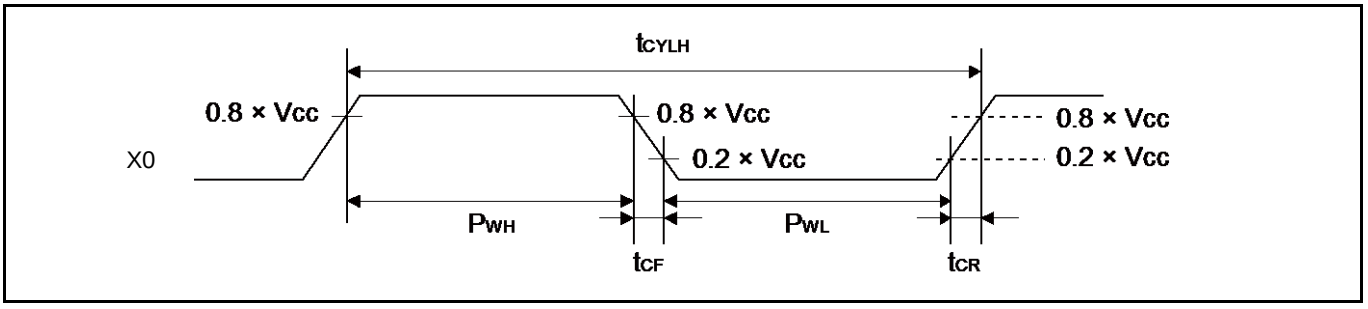
12.4.1 Main Clock Input Characteristics

(V_{CC} = AV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = 0V, T_A = -40°C to +105°C)

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Input frequency	f_{CH}	X0, X1	V_{CC} ≥4.5 V	4	48	MHz	When crystal oscillator is connected
			V_{CC} < 4.5 V	4	20		
			V_{CC} ≥4.5 V	4	48	MHz	When using external clock
			V_{CC} < 4.5 V	4	20		
Input clock cycle	t_{CYLH}		V_{CC} ≥4.5 V	20.83	250	ns	When using external clock
			V_{CC} < 4.5 V	50	250		
Input clock pulse width	-		P_{WH}/t_{CYLH}, P_{WL}/t_{CYLH}	45	55	%	When using external clock
Input clock rise time and fall time	t_{CF}, t_{CR}		-	-	5	ns	When using external clock
Internal operating clock *1 frequency	f_{CC}	-	-	-	180	MHz	Base clock (HCLK/FCLK)
	f_{CP0}	-	-	-	90	MHz	APB0bus clock *2
	f_{CP1}	-	-	-	180	MHz	APB1bus clock *2
	f_{CP2}	-	-	-	90	MHz	APB2bus clock *2
Internal operating clock *1 cycle time	t_{CYCC}	-	-	5.56	-	ns	Base clock (HCLK/FCLK)
	t_{CYCP0}	-	-	11.1	-	ns	APB0bus clock *2
	t_{CYCP1}	-	-	5.56	-	ns	APB1bus clock *2
	t_{CYCP2}	-	-	11.1	-	ns	APB2bus clock *2

1: For more information about each internal operating clock, see Chapter 2-1: Clock in FM4 Family Peripheral Manual Main Part (002-04856).

2: For more about each APB bus to which each peripheral is connected, see 1. S6E2G Series Block Diagram in this data sheet.



12.4.10 External Bus Timing

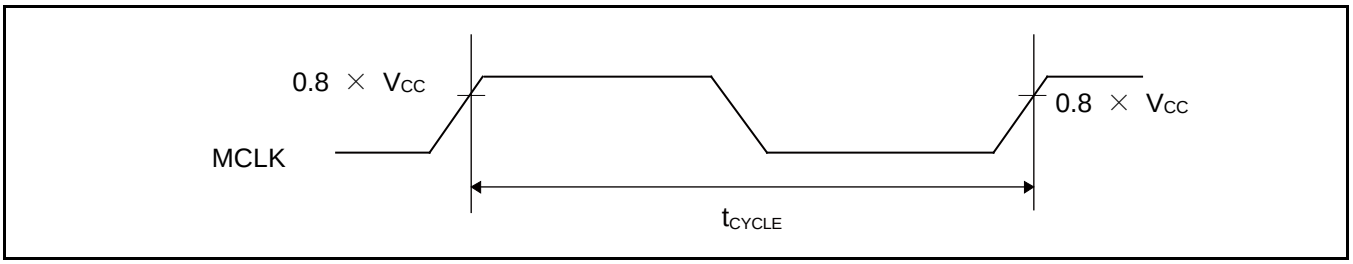
External Bus Clock Output Characteristics

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Output frequency	t_{CYCLE}	MCLKOUT *1		-	50 *2	MHz	

1: The external bus clock (MCLKOUT) is a divided clock of HCLK.

For more information about setting of clock divider, see Chapter 14: External Bus Interface in FM4 Family Peripheral Manual Main Part (002-04856).

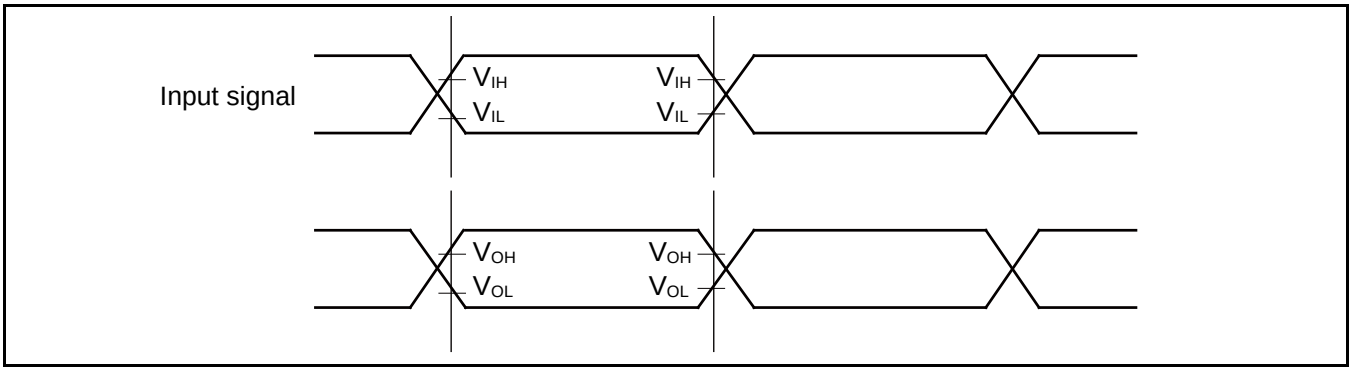
2: Generate MCLKOUT at setting more than four divisions when the AHB bus clock exceeds 100 MHz.



External Bus Signal I/O Characteristics

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Conditions	Value	Unit	Remarks
Signal input characteristics	V_{IH}	-	0.8 × V_{CC}	V	
	V_{IL}		0.2 × V_{CC}	V	
Signal output characteristics	V_{OH}		0.8 × V_{CC}	V	
	V_{OL}		0.2 × V_{CC}	V	



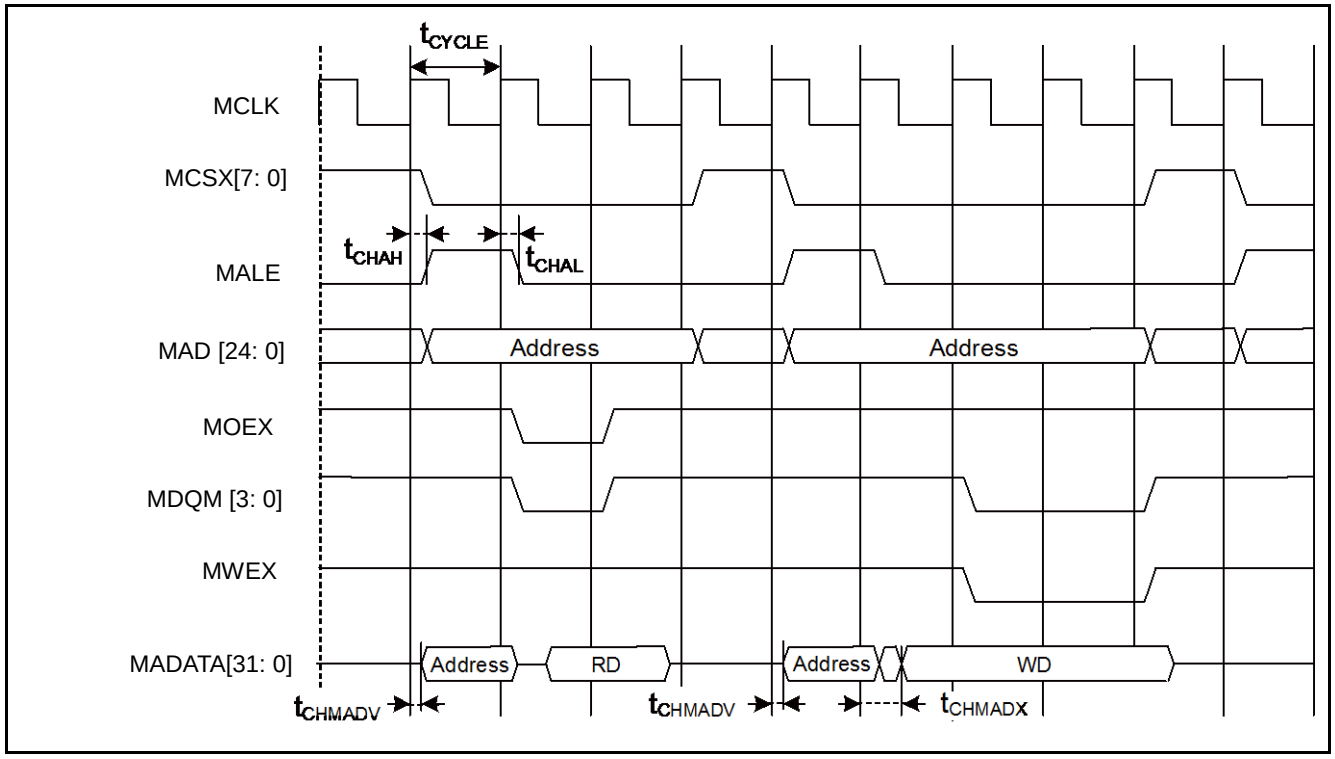
Multiplexed Bus Access Synchronous SRAM Mode

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
MALE delay time	t_{CHAL}	MCLK, MALE	-	1	9		
	t_{CHAH}		-	1	9		
MCLK ↑ →Multiplexed address delay time	t_{CHMADV}	MCLK, MADATA[31: 0]	-	1	t_{OD}	ns	
MCLK ↑ →Multiplexed data output time	t_{CHMADX}		-	1	t_{OD}	ns	

Note:

- *When the external load capacitance C_L = 30 pF*

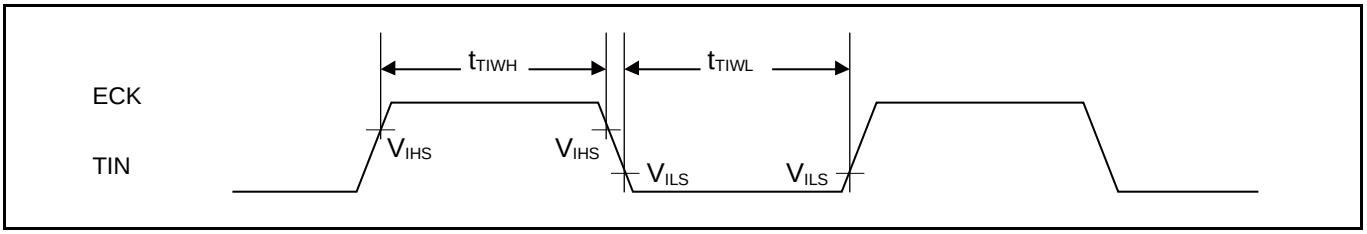


12.4.11 Base Timer Input Timing

Timer Input Timing

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

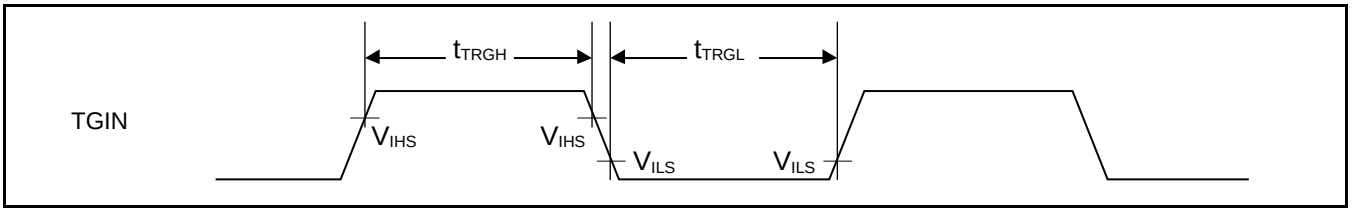
Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Input pulse width	t_{TIWH}, t_{TIWL}	TIOAn/TIOBn (when using as ECK, TIN)	-	$2t_{CYCP}$	-	ns	



Trigger Input Timing

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Input pulse width	t_{TRGH}, t_{TRGL}	TIOAn/TIOBn (when using as TGIN)	-	$2t_{CYCP}$	-	ns	



Note:

- *t_{CYCP} indicates the APB bus clock cycle time. For more information about the APB bus number to which the base timer is connected, see 1. S6E2G Series Block Diagram in this data sheet.*

When Using Synchronous Serial Chip Select (SCINV = 1, CSLVL = 0)

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Conditions	VCC < 4.5 V		VCC ≥ 4.5 V		Units
			Min	Max	Min	Max	
SCS ↑ →SCK ↑ setup time	t_{CSSI}	Internal shift clock operation	(*1)-50	(*1)+0	(*1)-50	(*1)+0	ns
SCK ↓ →SCS ↓ hold time	t_{CSHI}		(*2)+0	(*2)+50	(*2)+0	(*2)+50	ns
SCS deselect time	t_{CSDI}		(*3)-50 +5t_{CYCP}	(*3)+50 +5t_{CYCP}	(*3)-50 +5t_{CYCP}	(*3)+50 +5t_{CYCP}	ns
SCS ↑ →SCK ↑ setup time	t_{CSSE}	External shift clock operation	3t_{CYCP}+30	-	3t_{CYCP}+30	-	ns
SCK ↓ →SCS ↓ hold time	t_{CSHE}		0	-	0	-	ns
SCS deselect time	t_{CSDE}		3t_{CYCP}+30	-	3t_{CYCP}+30	-	ns
SCS ↑ →SOT delay time	t_{DSE}		-	40	-	40	ns
SCS ↓ →SOT delay time	t_{DEE}		0	-	0	-	ns

(*1): CSSU bit value×serial chip select timing operating clock cycle [ns]

(*2): CSHD bit value×serial chip select timing operating clock cycle [ns]

(*3): CSDS bit value×serial chip select timing operating clock cycle [ns]

Notes:

- *t_{CYCP} indicates the APB bus clock cycle time. For more information about the APB bus number to which the multi-function serial is connected, see 1. S6E2G Series Block Diagram in this data sheet.*
- *For more information about CSSU, CSHD, CSDS, and the serial chip select timing operating clock, see FM4 Family Peripheral Manual Main Part (002-04856).*
- *When the external load capacitance C_L = 30 pF.*

12.8 MainFlash Memory Write/Erase Characteristics

(V_{CC} = 2.7V to 5.5V)

Parameter		Value			Unit	Remarks
		Min	Typ	Max		
Sector erase time	Large Sector	-	0.7	3.7	s	Includes write time prior to internal erase
	Small Sector	-	0.3	1.1	s	
Half word (16-bit) write time	Write cycles ≤ 100 times	-	12	100	µs	Not including system-level overhead time
	Write cycles > 100 times			200		
Chip erase time*		-	13.6	68	s	Includes write time prior to internal erase

*: It indicates the chip erase time of 1MB MainFlash memory

For devices with 1.5 MB or 2 MB of MainFlash memory, two erase cycles are required.

See 3.2.2 Command Operating Explanations and 3.3.3 Flash Erase Operation in this product's Flash Programming Manual for the detail.

Write Cycles and Data Retention Time

Erase/Write Cycles (Cycle)	Data Retention Time (Year)
1,000	20*
10,000	10*
100,000	5*

*: This value comes from the technology qualification (using Arrhenius equation to translate high temperature acceleration test result into average temperature value at + 85°C).

Revision	ECN	Orig. of Change	Submission Date	Description of Change
				S6E2GM6JHAGV20000, S6E2GM8H0AGV20000, S6E2GM8HHAGV20000, S6E2GM8J0AGV20000, S6E2GM8JHAGV20000 Added MPNs below to “13. Ordering Information” (Page 185) S6E2G26H0AGV2000A, S6E2G26HHAGV2000A, S6E2G26J0AGV2000A, S6E2G26JHAGV2000A, S6E2G28H0AGV2000A, S6E2G28HHAGV2000A, S6E2G28J0AGV2000A, S6E2G28JHAGV2000A, S6E2G36H0AGV2000A, S6E2G36J0AGV2000A, S6E2G38H0AGV2000A, S6E2G38J0AGV2000A, S6E2GH6H0AGV2000A, S6E2GH6J0AGV2000A, S6E2GH8H0AGV2000A, S6E2GH8J0AGV2000A, S6E2GK6H0AGV2000A, S6E2GK6HHAGV2000A, S6E2GK6J0AGV2000A, S6E2GK6JHAGV2000A, S6E2GK8H0AGV2000A, S6E2GK8HHAGV2000A, S6E2GK8J0AGV2000A, S6E2GK8JHAGV2000A, S6E2GM6H0AGV2000A, S6E2GM6HHAGV2000A, S6E2GM6J0AGV2000A, S6E2GM6JHAGV2000A, S6E2GM8H0AGV2000A, S6E2GM8HHAGV2000A, S6E2GM8J0AGV2000A, S6E2GM8JHAGV2000A Modified typo about the munber of QPRC channels(from 4ch to 2ch) (Page 1,6,10) Modified the expression of the “Built-in CR” in “2. Product Lineup”(Page 6).